# 2SD1149

### Silicon NPN epitaxial planar type

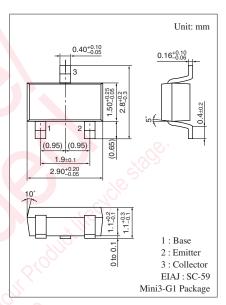
For low-frequency amplification

#### Features

- High forward current transfer ratio h<sub>FE</sub>
- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- High emitter-base voltage (Collector open)  $V_{EBO}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

Absolute Maximum Ratings $I_a = 25$ C					
Parameter	Symbol	Rating	Unit		
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	100	V		
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	100	v		
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	15	V		
Collector current	I <sub>C</sub>	20	mA		
Peak collector current	I <sub>CP</sub>	50	mA		
Collector power dissipation	P <sub>C</sub>	200	mW		
Junction temperature	Tj	150	°C		
Storage temperature	T <sub>stg</sub>	-55 to +150	S ℃		





#### Marking symbol: 1V

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

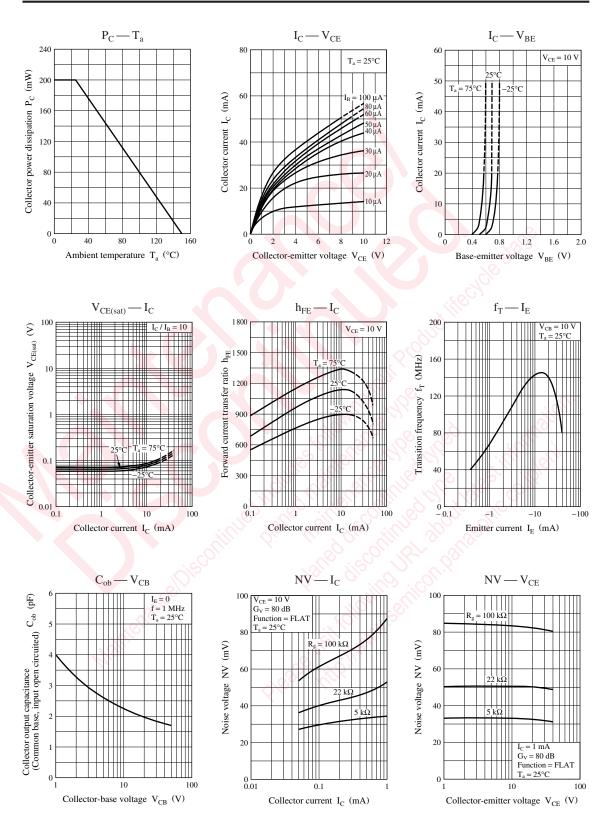
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	100			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	100			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	15			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 60 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 60 \text{ V}, I_B = 0$			1.0	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$	400		1 2 0 0	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$		0.05	0.20	V
Transition frequency	f <sub>T</sub>	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		100		MHz

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	R	S	
$h_{\rm FE}$	400 to 800	0 to 800 600 to 1 200	

### Panasonic



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